

# Silicon Carbide (SiC) Cascode JFET – EliteSiC, Power N-Channel, TO-263-7, 750 V, 58 mohm

# **UJ4C075060B7S**

# Description

The UJ4C075060B7S is a 750 V, 58 m $\Omega$  G4 SiC FET. It is based on unique 'cascode' circuit configuration, in which a normally-on SiC JFET is co-packaged with a Si MOSFET to produce a normally-off SiC FET device. The device's standard gate-drive characteristics allows for a true "drop-in replacement" to Si IGBTs, Si FETs, SiC MOSFETs or Si superjunction devices. Available in the TO-263-7 package, this device exhibits ultra-low gate charge and exceptional reverse recovery characteristics, making it ideal for switching inductive loads and any application requiring standard gate drive.

#### **Features**

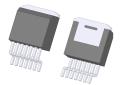
- On-Resistance  $R_{DS(on)}$ : 58 m $\Omega$  (typ)
- Operating Temperature: 175 °C (max)
- Excellent Reverse Recovery:  $Q_{rr} = 70 \text{ nC}$
- Low Body Diode V<sub>FSD</sub>: 1.31 V
- Low Gate Charge:  $Q_G = 37.8 \text{ nC}$
- Threshold Voltage V<sub>G(th)</sub>: 4.8 V (typ) Allowing 0 to 15 V Drive
- Low Intrinsic Capacitance
- ESD Protected: HBM Class 2
- TO-263-7 Package for Faster Switching, Clean Gate Waveforms

1

• This Device is Pb-Free, Halogen Free and is RoHS Compliant

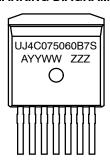
# **Typical Applications**

- EV Charging
- PV Inverters
- Switch Mode Power Supplies
- Power Factor Correction Modules
- Motor Drives
- · Induction Heating



TO-263-7 CASE 418BA

#### MARKING DIAGRAM

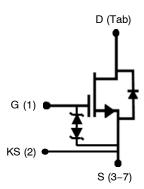


UJ4C075060B7S = Specific Device Number

A = Assembly Location

YY = Year WW = Work Week ZZZ = Lot ID

#### **PIN CONNECTIONS**



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 8 of this data sheet.

# **MAXIMUM RATINGS**

Symbol	Parameter	Test Conditions	Value	Unit
V <sub>DS</sub>	Drain-Source Voltage		750	V
V <sub>GS</sub>	Gate-Source Voltage	DC	-20 to +20	V
		AC (f > 1 Hz)	-25 to +25	V
I <sub>D</sub>	Continuous Drain Current (Note 1)	T <sub>C</sub> = 25 °C	25.8	Α
		T <sub>C</sub> = 100 °C	19	Α
I <sub>DM</sub>	Pulsed Drain Current (Note 2)	T <sub>C</sub> = 25 °C	76	Α
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 3)	L = 15 mH, I <sub>AS</sub> = 1.8 A	24.3	mJ
dv/dt	SiC FET dv/dt Ruggedness	V <sub>DS</sub> ≤ 500 V	200	V/ns
P <sub>tot</sub>	Power Dissipation	T <sub>C</sub> = 25 °C	128	W
T <sub>J,max</sub>	Maximum Junction Temperature		175	°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to 175	°C
T <sub>solder</sub>	Reflow Soldering Temperature	Reflow MSL 1	245	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Limited by  $T_{J,max}$ .

2. Pulse width  $t_p$  limited by  $T_{J,max}$ .

3. Starting  $T_J = 25$  °C.

# THERMAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		-	0.9	1.17	°C/W

# **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = +25 $^{\circ}$ C unless otherwise specified)

Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit
TYPICAL	PERFORMANCE – STATIC	•					•
BV <sub>DS</sub>	Drain-source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 1 \text{ mA}$		750	_	_	V
I <sub>DSS</sub>	Total Drain Leakage Current	V <sub>DS</sub> = 750 V, V <sub>GS</sub> = 0 V	V, T <sub>J</sub> = 25 °C	-	0.7	40	μΑ
		$V_{DS} = 750 \text{ V}, V_{GS} = 0 \text{ V}$	V, T <sub>J</sub> = 175°C	-	15	_	
I <sub>GSS</sub>	Total Gate Leakage Current	$V_{DS} = 0 \text{ V}, T_{J} = 25 \text{ °C}, \ V_{GS} = -20 \text{ V} / +20 \text{ V}$		-	4.7	±20	μΑ
R <sub>DS(on)</sub>	Drain-source On-resistance	V <sub>GS</sub> = 12 V, I <sub>D</sub> = 20 A	T <sub>J</sub> = 25 °C	_	58	74	mΩ
			T <sub>J</sub> = 125 °C	-	106	_	
			T <sub>J</sub> = 175 °C	-	147	-	
V <sub>G(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 5 V, I <sub>D</sub> = 10 mA		4	4.8	6	V
R <sub>G</sub>	Gate Resistance	f = 1 MHz, open drain		-	4.5	-	Ω
TYPICAL	PERFORMANCE - REVERSE DIODE						
I <sub>S</sub>	Diode Continuous Forward Current (Note 1)	T <sub>C</sub> = 25 °C		-	_	25.8	Α
I <sub>S,pulse</sub>	Diode Pulse Current (Note 2)	T <sub>C</sub> = 25 °C		_	_	76	Α
$V_{FSD}$	Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 10 A, T	<sub>J</sub> = 25 °C	-	1.31	1.75	V
		$V_{GS} = 0 \text{ V}, I_{S} = 10 \text{ A}, T$	<sub>J</sub> = 175 °C	_	1.8	-	
Q <sub>rr</sub>	Reverse Recovery Charge	$\begin{array}{c} V_{DS} = 400 \; V, \; I_{S} = 20 \; A, \; V_{GS} = 0 \; V, \\ R_{G \; EXT} = 20 \; \Omega, \; di/dt = 1200 \; A/\mu s, \\ T_{J} = 25 \; ^{\circ} C \end{array}$		-	70	_	nC
t <sub>rr</sub>	Reverse Recovery Time			-	11	=	ns
$Q_{rr}$	Reverse Recovery Charge	$V_{DS} = 400 \text{ V}$ , $I_{S} = 20 \text{ A}$ , $V_{GS} = 0 \text{ V}$ , $R_{G EXT} = 20 \Omega$ , $di/dt = 1200 \text{ A}/\mu \text{s}$ , $T_{1} = 150 \text{ °C}$		-	77	-	nC
t <sub>rr</sub>	Reverse Recovery Time			_	13	_	ns

# **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = +25 °C unless otherwise specified) (continued)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
TYPICAL	PERFORMANCE – DYNAMIC					
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 400 V, V <sub>GS</sub> = 0 V,	-	1420	-	pF
Coss	Output Capacitance	f = 100 kHz	-	41	-	
C <sub>rss</sub>	Reverse Transfer Capacitance		_	2.7	_	
C <sub>oss(er)</sub>	Effective Output Capacitance, Energy Related	V <sub>DS</sub> = 0 V to 400 V, V <sub>GS</sub> = 0 V	-	50	-	pF
C <sub>oss(tr)</sub>	Effective Output Capacitance, Time Related		-	94	-	pF
E <sub>oss</sub>	C <sub>OSS</sub> Stored Energy	V <sub>DS</sub> = 400 V, V <sub>GS</sub> = 0 V	-	4	-	μJ
$Q_{G}$	Total Gate Charge	V <sub>DS</sub> = 400 V, I <sub>D</sub> = 20 A,	-	37.8	-	nC
$Q_{GD}$	Gate-Drain Charge	V <sub>GS</sub> = 0 V to 15 V	_	8	_	
Q <sub>GS</sub>	Gate-Source Charge		_	11.8	_	
t <sub>d(on)</sub>	Turn-on Delay Time	Notes 4	_	15	_	ns
t <sub>r</sub>	Rise Time	V <sub>DS</sub> = 400 V, I <sub>D</sub> = 20 A, Gate Driver = 0 V to +15 V,	_	21	_	
t <sub>d(off)</sub>	Turn-off Delay Time	Turn-on $R_{G EXT} = 1 \Omega$ ,	-	75	_	
t <sub>f</sub>	Fall Time	Turn-off $R_{G,EXT} = 20 \Omega$ ,	_	11	_	
E <sub>ON</sub>	Turn-on Energy	Inductive Load, FWD: same device with	_	132	_	μJ
E <sub>OFF</sub>	Turn-off Energy	$V_{GS} = 0 \text{ V}$ and $R_{G} = 20 \Omega$ , $T_{J} = 25 ^{\circ}\text{C}$	_	29	_	,
E <sub>TOTAL</sub>	Total Switching Energy		_	161	_	
t <sub>d(on)</sub>	Turn-on Delay Time	Notes 4	_	12	_	ns
t <sub>r</sub>	Rise Time	$V_{DS}$ = 400 V, $I_{D}$ = 20 A, Gate Driver = 0 V to +15 V, Turn-on $R_{G,EXT}$ = 1 $\Omega$ , Turn-off $R_{G,EXT}$ = 20 $\Omega$ , Inductive Load, FWD: same device with	_	23	_	
t <sub>d(off)</sub>	Turn-off Delay Time		_	83	_	
t <sub>f</sub>	Fall Time		_	12	_	
E <sub>ON</sub>	Turn-on Energy		_	148	_	μJ
E <sub>OFF</sub>	Turn-off Energy	$V_{GS} = 0 \text{ V and } R_G = 20 \Omega,$	_	37	_	
E <sub>TOTAL</sub>	Total Switching	T <sub>J</sub> = 150 °C	_	185	_	
t <sub>d(on)</sub>	Turn-on Delay Time	Notes 5 and 6	_	10	_	ns
t <sub>r</sub>	Rise Time	$V_{DS} = 400 \text{ V}, I_{D} = 20 \text{ A},$	_	22	_	
t <sub>d(off)</sub>	Turn-off Delay Time	Gate Driver = 0 V, to +15 V, Turn-on $R_{G,EXT}$ = 1 $\Omega$ ,	_	32	_	
t <sub>f</sub>	Fall Time	Turn-off $R_{G,EXT} = 5 \Omega$ ,	_	8	_	
E <sub>ON</sub>	Turn-on Energy Including R <sub>S</sub> Energy	Inductive Load, FWD: same device with	_	96	_	μJ
E <sub>OFF</sub>	Turn-off Energy Including R <sub>S</sub> Energy	$V_{GS} = 0 \text{ V}$ and $R_{G} = 5 \Omega$ ,	_	36	_	,
E <sub>TOTAL</sub>	Total Switching Energy	RC snubber: $R_S = 10 \Omega$ and $C_S = 100 pF$ , $T_J = 25 °C$	_	132	_	
E <sub>RS_ON</sub>	Snubber R <sub>S</sub> Energy During Turn-on		_	0.7	_	
E <sub>RS_OFF</sub>	Snubber R <sub>S</sub> Energy During Turn-off		_	1	_	
t <sub>d(on)</sub>	Turn-on Delay Time	Notes 5 and 6	+ -	14	_	ns
t <sub>r</sub>	Rise Time	Notes 3 and 0 $V_{DS} = 400 \text{ V}$ , $I_D = 20 \text{ A}$ , $I_D = 20 \text$	_	23	_	
t <sub>d(off)</sub>	Turn-off Delay Time		_	45	_	
t <sub>f</sub>	Fall Time		_	10	_	
E <sub>ON</sub>	Turn-on Energy Including R <sub>S</sub> Energy		_	140	_	μJ
E <sub>OFF</sub>	Turn-off Energy Including R <sub>S</sub> Energy		<del>-</del>	25	_	μο
E <sub>TOTAL</sub>	Total Switching Energy		<del>-</del>	165	_	
_	Snubber R <sub>S</sub> Energy During Turn-on			0.7	_	
E <sub>RS_ON</sub>	Snubber R <sub>S</sub> Energy During Turn-off		<del>-</del>	1		
E <sub>RS_OFF</sub>	ametric performance is indicated in the Electrica			ļ	_	<u> </u>

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

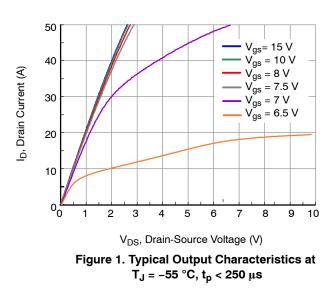
4. Measured with the half-bridge mode switching test circuit in Figure 23.

5. Measured with the half-bridge mode switching test circuit in Figure 24.

6. The switching energies (turn-on energy, turn-off energy and total energy) presented in this table include the device RC snubber energy

- losses.

#### **TYPICAL PERFORMANCE DIAGRAMS**



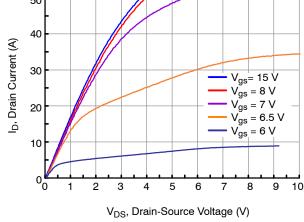


Figure 2. Typical Output Characteristics at  $T_J = 25~^{\circ}\text{C}, \, t_p < 250~\mu\text{s}$ 

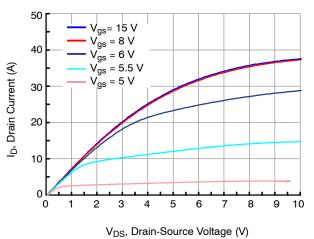


Figure 3. Typical Output Characteristics at  $T_{J}$  = 175  $^{\circ}C,\,t_{p}<$  250  $\mu s$ 

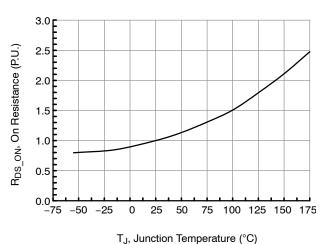


Figure 4. Normalized On-Resistance vs. Temperature at  $V_{GS} = 12 \text{ V}$  and  $I_D = 20 \text{ A}$ 

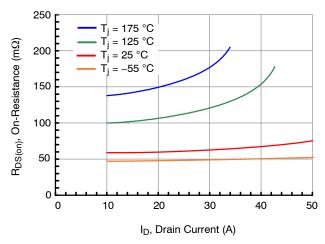


Figure 5. Typical Drain-Source On-Resistances at  $V_{GS} = 12 \text{ V}$ 

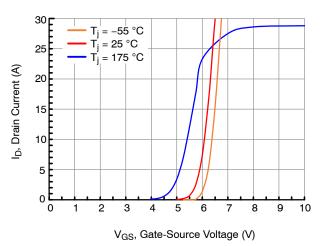


Figure 6. Typical Transfer Characteristics at  $V_{DS} = 5 \text{ V}$ 

# TYPICAL PERFORMANCE DIAGRAMS (continued)

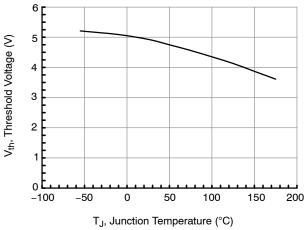


Figure 7. Threshold Voltage vs. Junction Temperature at  $V_{DS}$  = 5 V and  $I_{D}$  = 10 mA

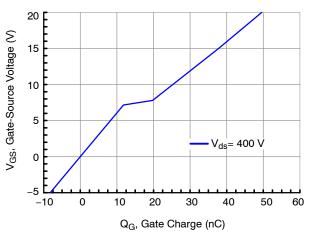


Figure 8. Typical Gate Charge at I<sub>D</sub> = 20 A

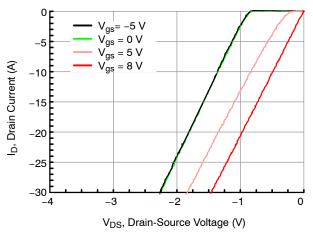


Figure 9.  $3^{rd}$  Quadrant Characteristics at  $T_J = -55$  °C

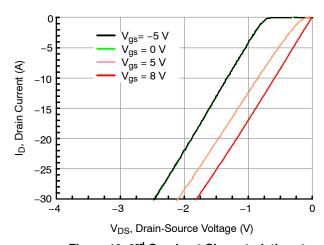


Figure 10.  $3^{rd}$  Quadrant Characteristics at  $T_J = 25$  °C

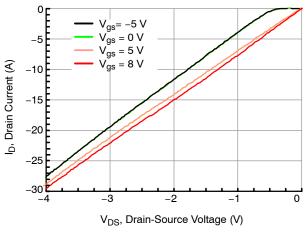


Figure 11.  $3^{rd}$  Quadrant Characteristics at  $T_J = 175$  °C

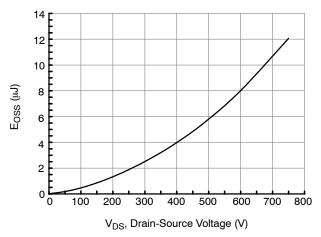


Figure 12. Typical Stored Energy in  $C_{OSS}$  at  $V_{GS} = 0 \text{ V}$ 

# TYPICAL PERFORMANCE DIAGRAMS (continued)

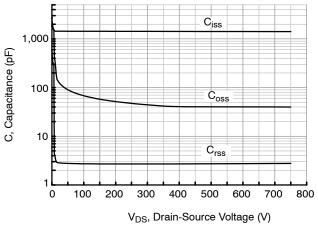


Figure 13. Typical Capacitances at f = 100 kHz and  $V_{GS}$  = 0 V

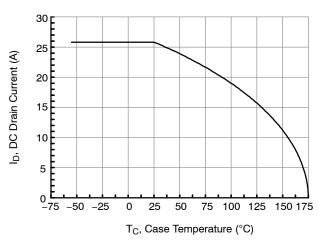


Figure 14. DC Drain Current Derating

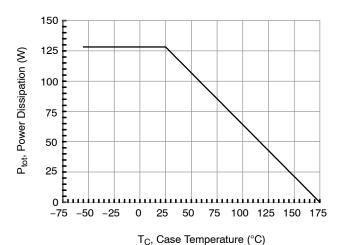


Figure 15. Total Power Dissipation

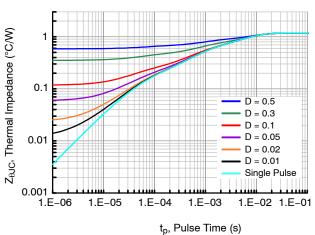


Figure 16. Maximum Transient Thermal Impedance

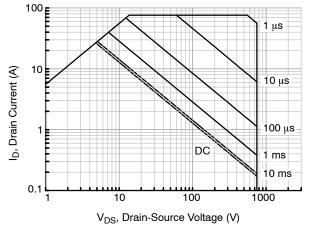


Figure 17. Safe Operation Area at  $T_C$  = 25 °C, D = 0, Parameter  $t_p$ 

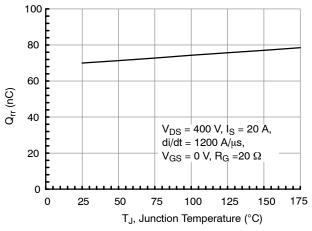


Figure 18. Reverse Recovery Charge Q<sub>rr</sub> vs. Junction Temperature

#### TYPICAL PERFORMANCE DIAGRAMS (continued)

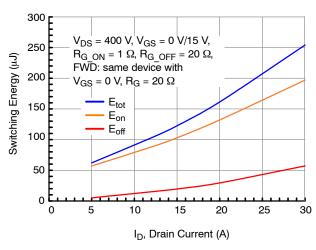
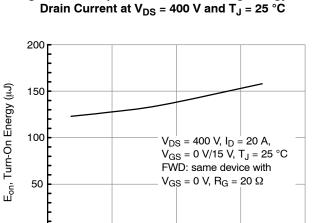


Figure 19. Clamped Inductive Switching Energy vs. Drain Current at V<sub>DS</sub> = 400 V and T<sub>J</sub> = 25 °C



 $R_{G\ EXT}$ , Total External Turn-On  $R_{G\ }(\Omega)$ 

10

15

20

5

Figure 21. Clamped Inductive Switching Turn-On Energy vs. R<sub>G.EXT ON</sub>

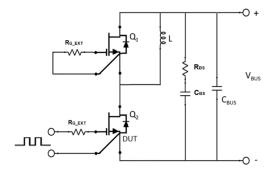


Figure 23. Schematic of the Half-Bridge Mode Switching Test Circuit. Note, a Bus RC Snubber (R<sub>BS</sub> = 2.5  $\Omega$ , C<sub>BS</sub> = 100 nF) is Used to Reduce the Power Loop High.

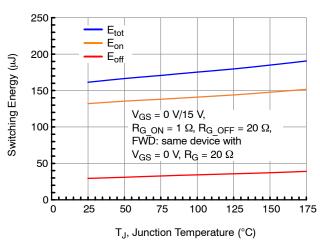


Figure 20. Clamped Inductive Switching Energy vs. Junction Temperature at  $V_{DS}$  = 400 V, and  $I_D$  = 20 A

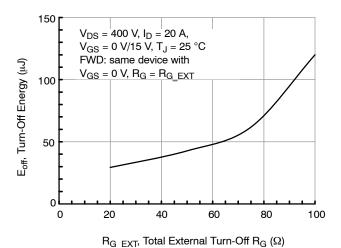


Figure 22. Clamped Inductive Switching Turn-Off Energy vs.  $R_{G,EXT\_OFF}$ 

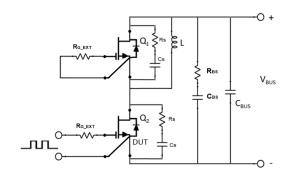


Figure 24. Schematic of the Half-Bridge Mode **Switching Test Circuit with Device RC Snubbers** (R<sub>S</sub> = 10  $\Omega$ , C<sub>S</sub> = 100 pF) and a bus RC Snubber  $(R_{BS} = 2.5 \Omega, C_{BS} = 100 nF).$ 

#### **APPLICATIONS INFORMATION**

SiC FETs are enhancement-mode power switches formed by a high-voltage SiC depletion-mode JFET and a low-voltage silicon MOSFET connected in series. The silicon MOSFET serves as the control unit while the SiC JFET provides high voltage blocking in the off state. This combination of devices in a single package provides compatibility with standard gate drivers and offers superior performance in terms of low on-resistance ( $R_{DS(on)}$ ), output capacitance ( $C_{oss}$ ), gate charge ( $Q_G$ ), and reverse recovery charge ( $Q_{rr}$ ) leading to low conduction and switching losses. The SiC FETs also provide excellent reverse conduction capability eliminating the need for an external anti-parallel diode.

Like other high performance power switches, proper PCB layout design to minimize circuit parasitics is strongly recommended due to the high dv/dt and di/dt rates. An external gate resistor is recommended when the FET is

working in the diode mode in order to achieve the optimum reverse recovery performance. For more information on SiC FET operation, see <a href="https://www.onsemi.com">www.onsemi.com</a>.

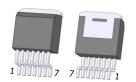
A snubber circuit with a small  $R_{(G)}$ , or gate resistor, provides better EMI suppression with higher efficiency compared to using a high  $R_{(G)}$  value. There is no extra gate delay time when using the snubber circuitry, and a small  $R_{(G)}$  will better control both the turn-off  $V_{(DS)}$  peak spike and ringing duration, while a high  $R_{(G)}$  will damp the peak spike but result in a longer delay time. In addition, the total switching loss when using a snubber circuit is less than using high  $R_{(G)}$ , while greatly reducing  $E_{(OFF)}$  from mid-to-full load range with only a small increase in  $E_{(ON)}$ . Efficiency will therefore improve with higher load current. For more information on how a snubber circuit will improve overall system performance, visit the **onsemi** website at www.onsemi.com.

#### **ORDERING INFORMATION**

Part Number	Marking	Package	Shipping <sup>†</sup>
UJ4C075060B7S	UJ4C075060B7S	TO-263-7 (Pb-Free, Halogen Free)	800 units / Tape and Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



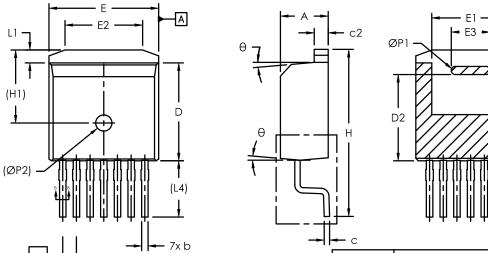


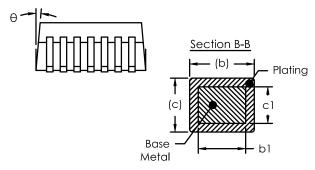
#### TO-263-7 10.18x9.08x4.43, 1.27P CASE 418BA ISSUE B

**DATE 17 APR 2025** 

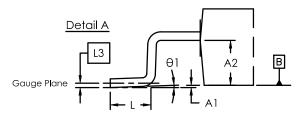
D1

(H3)





**⊕** 0.25mm **M** B A **M** 



NI	<u> </u>	tes	
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- 1. Dimensioning and Tolerancing as per ASME Y14.5M, 2018.
- 2. Controlling Dimension: Millimeters
- 3. Package body sides exclude mold flash and gate burrs.
- 4. Dimension L is measured on gauge plane.
- 5. Dimension c1 and b1 applies to base metal only.

Min         Nom         Max           A         4.30         4.43         4.56           A1         0.00         0.13         0.25           A2         2.45         2.60         2.75           b         0.50         0.60         0.70           b1         0.50         -         -           c         0.40         -         -           c2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF         1.42           L1         0.98         1.20         1.42           L3         0.25 BSC         1.44	SYM		MILLIMETERS			
A1       0.00       0.13       0.25         A2       2.45       2.60       2.75         b       0.50       0.60       0.70         b1       0.50       -       -         c       0.40       0.50       0.60         c1       0.40       -       -         c2       1.20       1.30       1.40         D       8.93       9.08       9.23         D1       5.85       6.00       6.15         D2       7.90       8.00       8.10         e       1.27 BSC         E       10.08       10.18       10.28         E1       6.82       7.22       7.62         E2       6.50       7.55       8.60         E3       3.50       3.60       3.70         H       15.00       15.50       16.00         H1       6.78 REF         H3       7.30 REF         L       1.90       2.20       2.50         L1       0.98       1.20       1.42         L3       0.25 BSC       1.44       5.22 REF         ØP1       0.65       0.75       0.85	311/1	Min	Nom	Мах		
A2       2.45       2.60       2.75         b       0.50       0.60       0.70         b1       0.50       -       -         c       0.40       0.50       0.60         c1       0.40       -       -         c2       1.20       1.30       1.40         D       8.93       9.08       9.23         D1       5.85       6.00       6.15         D2       7.90       8.00       8.10         e       1.27 BSC         E       10.08       10.18       10.28         E1       6.82       7.22       7.62         E2       6.50       7.55       8.60         E3       3.50       3.60       3.70         H       15.00       15.50       16.00         H1       6.78 REF         H3       7.30 REF         L       1.90       2.20       2.50         L1       0.98       1.20       1.42         L3       0.25 BSC       1.4       5.22 REF         ØP1       0.65       0.75       0.85         ØP2       1.50 REF       5°	Α	4.30	4.43	4.56		
b         0.50         0.60         0.70           b1         0.50         -         -           c         0.40         0.50         0.60           c1         0.40         -         -           c2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF	A1	0.00	0.13	0.25		
b1         0.50         -         -           c         0.40         0.50         0.60           c1         0.40         -         -           c2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF         5°	A2	2.45	2.60	2.75		
C         0.40         0.50         0.60           c1         0.40         -         -           c2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC         E           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF         5°	b	0.50	0.60	0.70		
C1         0.40         -         -           C2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.         L         1.90         2.20         2.50           L1         0.98         1.20         1.42         1.42           L3         0.25 BSC         1.42         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF         5°	b1	0.50	-	=		
C2         1.20         1.30         1.40           D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF           6         5°	С	0.40	0.50	0.60		
D         8.93         9.08         9.23           D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF           Θ         5°	c1	0.40	-	-		
D1         5.85         6.00         6.15           D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF           6         5°	c2	1.20	1.30	1.40		
D2         7.90         8.00         8.10           e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF           Θ         5°	D	8.93	9.08	9.23		
e         1.27 BSC           E         10.08         10.18         10.28           E1         6.82         7.22         7.62           E2         6.50         7.55         8.60           E3         3.50         3.60         3.70           H         15.00         15.50         16.00           H1         6.78 REF           H3         7.30 REF.           L         1.90         2.20         2.50           L1         0.98         1.20         1.42           L3         0.25 BSC           L4         5.22 REF           ØP1         0.65         0.75         0.85           ØP2         1.50 REF           Θ         5°	D1	5.85	6.00	6.15		
E 10.08 10.18 10.28 E1 6.82 7.22 7.62 E2 6.50 7.55 8.60 E3 3.50 3.60 3.70 H 15.00 15.50 16.00 H1 6.78 REF H3 7.30 REF. L 1.90 2.20 2.50 L1 0.98 1.20 1.42 L3 0.25 BSC L4 5.22 REF ØP1 0.65 0.75 0.85 ØP2 1.50 REF	D2	7.90	8.00	8.10		
E1 6.82 7.22 7.62 E2 6.50 7.55 8.60 E3 3.50 3.60 3.70 H 15.00 15.50 16.00 H1 6.78 REF H3 7.30 REF. L 1.90 2.20 2.50 L1 0.98 1.20 1.42 L3 0.25 BSC L4 5.22 REF ØP1 0.65 0.75 0.85 ØP2 1.50 REF		1.27 BSC				
E2       6.50       7.55       8.60         E3       3.50       3.60       3.70         H       15.00       15.50       16.00         H1       6.78 REF         H3       7.30 REF.         L       1.90       2.20       2.50         L1       0.98       1.20       1.42         L3       0.25 BSC         L4       5.22 REF         ØP1       0.65       0.75       0.85         ØP2       1.50 REF         Θ       5°	Е	10.08	10.18	10.28		
E3 3.50 3.60 3.70  H 15.00 15.50 16.00  H1 6.78 REF  H3 7.30 REF.  L 1.90 2.20 2.50  L1 0.98 1.20 1.42  L3 0.25 BSC  L4 5.22 REF  ØP1 0.65 0.75 0.85  ØP2 1.50 REF  Θ 5°	E1	6.82	7.22	7.62		
H 15.00 15.50 16.00  H1 6.78 REF  H3 7.30 REF.  L 1.90 2.20 2.50  L1 0.98 1.20 1.42  L3 0.25 BSC  L4 5.22 REF  ØP1 0.65 0.75 0.85  ØP2 1.50 REF  Θ 5°	E2	6.50	7.55	8.60		
H1 6.78 REF H3 7.30 REF.  L 1.90 2.20 2.50  L1 0.98 1.20 1.42  L3 0.25 BSC  L4 5.22 REF  ØP1 0.65 0.75 0.85  ØP2 1.50 REF  Θ 5°	E3	3.50	3.60	3.70		
H3 7.30 REF.  L 1.90 2.20 2.50  L1 0.98 1.20 1.42  L3 0.25 BSC  L4 5.22 REF  ØP1 0.65 0.75 0.85  ØP2 1.50 REF  Θ 5°	Н	15.00	15.50	16.00		
L 1.90 2.20 2.50 L1 0.98 1.20 1.42 L3 0.25 BSC L4 5.22 REF  ØP1 0.65 0.75 0.85  ØP2 1.50 REF  θ 5°	H1		6.78 REF			
L1     0.98     1.20     1.42       L3     0.25 BSC       L4     5.22 REF       ØP1     0.65     0.75     0.85       ØP2     1.50 REF       Θ     5°	Н3		7.30 REF.			
L3     0.25 BSC       L4     5.22 REF       ØP1     0.65     0.75     0.85       ØP2     1.50 REF       Θ     5°		1.90	2.20	2.50		
L4     5.22 REF       ØP1     0.65     0.75     0.85       ØP2     1.50 REF       Θ     5°	L1	0.98	1.20	1.42		
ØP1         0.65         0.75         0.85           ØP2         1.50 REF           θ         5°	L3					
ØP2 1.50 REF Θ 5°	L4	5.22 REF				
θ 5°	ØP1	0.65 0.75 0.85				
	ØP2					
01 20	θ					
	θ1	3°				

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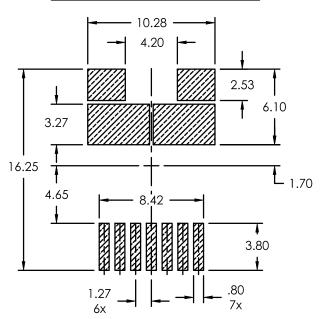
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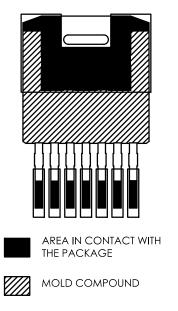
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